Diode Semiconductor Device - Page 1 of 1



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Inc	losure Material:
Gla	ass
Ov	erall Length:
0.2	20 inches
Te	rminal Length:
1.0	00 inches
Ov	erall Diameter:
0.0	90 inches
Мо	ounting Method:
Те	rminal
Fea	atures Provided:
He	rmetically sealed case
Se	miconductor Material:
Sili	con
Po	wer Rating Per Characteristic:
150	0.0 milliwatts small-signal input power, common-collector preset
Te	rminal Type And Quantity:
2 u	ninsulated wire lead
Sh	elf Life:
N/a	à
Un	it Of Measure:
De	militarization:
No	
Fii	g:
A1	10a0